是一个人,我们就是一个人,但是我们的人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是

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ACCESSION NR: AP3003971

are shown in Fig. 1 of the Enclosure along with the results calculated by the method of moments (shown by the solid line). The measured spectre were found to be in good agreement with theoretical results for all thicknesses of the polyethylene layer at $E_{\rm n}>3{\rm Mev}$. At $E_{\rm n}<3{\rm Mev}$ a divergence between the experimental and calculated results was noted. However, the tendency for a change in spectra with an increase in layer thickness in this energy range was the same for both calculated and experimental spectra. At neutron energies from 3 to 4 Mev and polyethylene thicknesses greater than 20 g/cm², the curve of the measured spectra showed a sharper dip than that of the calculated spectra. This is probably due to some inaccuracy in selecting or averaging the cross sections during calculation. The sharper dip in the curve was also noted in neutron spectra measured in water. "The authors thank their coworkers who serviced the reactor and laboratory assistants who assisted in the carrying out of experiments." Orig. art. has: 1 figure.

ASSCCIATION: none

SUBMITTED: 25Aug62

DATE ACQ: 08Aug63

ENCL: - 01

Card 2/32

NO REF SOV: 003

OTHER: 002

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ACCESSION NR: AT4019060

\$/0000/63/000/000/0260/0270

AUTHOR: Avayev, V. N.; Vasil'yev, G. A.; Yegorov, Yu. A.; Kucheryayev, V. A.; Orlov, Yu. V.; Pankrat'yev, Yu. V.; Panov, Ye. A

TITLE: Counters and dosimeters for the study of shielding and shielding properties of materials

SOURCE: Voprosy* fiziki zashchity* reaktorov; sbornik statey (Problems in physics of reactor shielding, collection of articles). Moscow, Gosatomizdat, 1963, 260-270

TOPIC TAGS: counter, scintillation counter, dosimeter, shielding, reactor shielding, nuclear reactor, gamma ray, neutron

ABSTRACT: In the study of the shielding properties of different materials and their combinations, it is important to know the following parameters: coefficients of attenuation of Y-ray and neutron streams of different energies; coefficients of attenuation of the power level of Y-radiation and fast neutrons; yield and spectrum of captured Y-radiation; activation of materials in a neutrons flux; and deformation of the Y-ray and neutron spectra in their passage through the material. Since existing equipment is insufficient for shielding studies, the authors built and tested a number of scintillation counters and dosimeters.

Card 1/3

ACCESSION NR: AT4019060

Among those described are a scintillation counter and spectrometer for the study of the attenuation of 6-ray flux, consisting of a FEU-11B photomultiplier with an NaI(T1) crystal (diameter and height 40 mm) mounted in a housing lined with aluminum foil, and a scintillation neutron counter consisting of a FEU-11B photomultiplier with plastic scintillator of ZnS(Ag) + lucite (diameter 30, height 10 mm). For neutron energies ≥ 2 MeV, the 6-ray background is calibrated with a Co60 source and eliminated by the proper bias in the analyzer. A similar neutron counter can be used as a monitor. A light guide in conjunction with a smaller counter is used when the opening in the shielding is too small. This light guide is made of organic glass (length 60, diameter 10 mm) and is equipped with a light collector (Tove, P. A. Rev. of Sci. Inst. 27, 143 (1956)). For neutron energies between 1 and 10 Mev, a stilbene crystal is used (diameter 30, height 20 mm) equipped with the &-discrimination arrangement described by H. W. Broch (Rev. Sci Instr. 31, 1063 (1960)). The detection efficiency for neutrons between 1 and 10 Mev is 10 - 2%. For thermal neutron detection, a FEU-29 or FEU-31 photomultiplier with an Li₂O- 3SiO₂ glass scintillator is used. Detection is based on the reaction Li6 + n + a + H3. The sensitivity of these counters to & rays is calibrated by Zn65 to Co60 sources. All-wave-length neutron counters are constructed as gas counters (type SNM-5) filled with BF3 and enclosed in paraffin, which is lined on the outside with cadmium. Dosimeters for fast neutrons are

Card 2/3

ACCESSION NR: AT4019060

made from plastic scintillators (polystyrene + terphenyl + ROROR) attached to a FEU-25 photomultiplier. The photomultiplier current is integrated and amplified by a direct current amplifier. The maximum sensitivity of this dosimeter is $0.2\,\mu$ F/sec per division. In order to eliminate %-ray background, the measurements are made simultaneously with a %-ray dosimeter which is a combination of the plastic and inorganic scintillators. A crystal of CsI(T1) (volume 1.5 cm³) is mounted on the axis of the plastic crystal (polystyrene + terphenyl + ROROR). Finally, a universal stand for detection and power supply is described. "The authors thank V. M. Isakov, D. I. Chupy*rin, A. I. Vasil'yev, V.N. Kozy*rev and Yu. G. Anisimov for taking part in the construction and adjustment of the apparatus." Orig. art. has: 9 figures and 1 table.

ASSOCIATION: none

SUBMITTED: 14Aug63

DATE ACQ: 27Feb64

ENCL: 00

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NO REF SOV: 015

OTHER; 004

Card 3/3

0, 4. - 5 - 12/102 0121/0127 ACCESSION NE ATSOUNTS Author - Vastifer, T. A. Cose & ..., ... Legorov, Tu. A. Kulheryayer, With Panklat 2004 TITLE: Attenuation of reactor rastation by seconding concrete SCURCE: Atombava energivi, v. 14, no. 2, 1465, 121-120 TOPIC TAGS: reactor radiation, radiation snielding, serpentine concrete, biological shielding, fast neutrons, gamma radiation, reactor shielding ABSTRACT: The shielding characteristics of concrete (density, 2.2 t/m3) with serpentine aggregate (introduced as sand or gravel) were studied in a water-moderated water-cooled research reactor. The shatial flux distribution of fast neutrons under conditions of semi-infinite geometry was measured with radioactive threshold indicators made of indium, phosphorus, and aluminum. Spectra of fast neutrons were measured behind concrete barriers 0, 10, 30, 60, and 100 cm thick, and it was established that the greatest apecitim deformation takes place in the 3-development in this elergy region, sharp irregularities were Card 1/2

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APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001858820017-1"

VASIL'YEV, G.A., kand. tekh. nauk (Rostov-na-Donu)

Hydrodynamic interrelation of the inlet apertures of baffles and of the area of sedimentation of horizontal settling tanks. Vod. i san. tekh. no.1:9-12 Ja '66.

(MINA 19:1)

VASIL'YEV, G.A., kand. ekonom. nauk

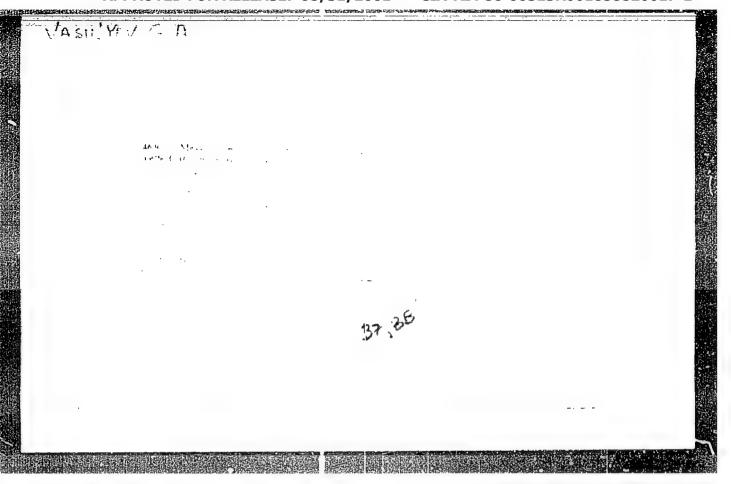
Automatic lines composed of machine-tool units. Standartizatsiia 29 no.6:7-9 Je '65. (NIRA 18:12)

VASIL'YEV, G.A.: VESELKIN, A.F.; YEGCROV, Yu.A.; MCISEYEV, G.C.;
PANKRAT'YEV, Yu.V.

Moderation of reactor radiations in serpentine sand. Atom. energ. 19 no.4:354-359 0 '65. (MIRA 18:11)

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Hornjury , 11

USSR/Electronics - Frequency Stabilizers

FD-2224

Card 1/1

Pub 90-4/12

Author

: Barchukov, A. I., Vasil'ev, G. A., Zhabotinskiy, M. E., Osipov. B. D.

Title

: Electromechanic klystron frequency stabilizer

Periodical: Radiotekhnika, 10, 29-32, Mar 1955

Abspect

: The article describes results of testing an electromechanic klystron frequency stabilizer developed by the authors at the Physics Institute imeni P. N. Lebedev of the Academy of Sciences USSR in 1951. The aim of this research was to develop a stabilizer simple in construction and operation, which could also provide an easy means for the klystron frequency changes. To attain these prerequisites in a single block, the functions of cavity resonator and the discriminator were unified, and the modulation of resonext frequency of the cavity-resonator wavemeter was executed by means of a

movable membrane.

Institution: Physics Institute imeni P. N. Lebedev, Academy of Sciences USSR

Submitted: 16 Apr 1954

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001858820017-1"

VASIL'YÉV, G. A.

"Investigation of the Transient Characteristics of Photo-Multipliers by Means of a Micro-Oscillograph"

A conference on Electron and Phot-electron Multiplier; Radiotkehnika i Elektronika, 1957, Vol. II, No. 12, pp. 1552 - 1557 (USSR)

Abst: A conference took place in Moscow during February 28 and March 6, 1957 and was attended by scientists and engineers from Moscow, Leningrad, Kiev and other centres of the Soviet Union. Altogether, 28 papers were read and discussed.

VESIL YEV, G. A.

AUTHOR: Vasil'yev, G.A.

120-4-18/35

TITIE:

Investigation of the Shape and Duration of Pulses from Photo-multipliers \$\phi \text{Y}-19M\$ and \$\phi \text{Y}-1B\$ Using a Micro-oscillograph (Issledovaniye formy i dlitel'nosti impul'sov fotoumnozhiteley FEU-19M and FEU-1V s pomoshch'yu mikro-ostsillografa)

PERIODICAL: Pribory i Tekhnika Eksperimenta, 1957, No.4, pp. 66 - 67 (USSR)

ABSTRACT: The simplest method of investigation of the shape and duration of photo-multiplier pulses is direct oscillography. However, usual types of CRTs do not allow oscillograms of pulses with amplitudes ~ 1 V to be obtained without using amplifiers, and the construction of amplifiers with a frequency band greater than 300 Mc/s presents quite a difficult problem. In this connection, micro-oscillographs are of interest because they permit a substantial increase in the deflection sensitivity but still preserve the necessary writing speed. Micro-oscillographs have been known for some time (Ardenne, 1938) but have obtained only a limited application (Refs. 1 and 2) on account of the relatively complicated practical requirements. In this investigation, a micro-oscillographic tube with distributed Cardl/5 deflection systems, as developed by Ardenne and his colleagues

120-4-18/35

Investigation of the Shape and Duration of Pulses from Photomultipliers \$\phi \gamma Y-19M and \$\phi \gamma Y-1B using a Micro-oscillograph.

> in 1954 (Ref.3) was used. This tube has a deflection sensitivity \sim 0.25 V for the thickness of a line, which on a photoplate comprises 10 - 12 μ . The tube operates with an accelerating voltage of 30 kV.

The deflection system consists of an artificial line (5 sections) with a mean frequency of 2 600 Mc/s, terminated with its characteristic impedance (100 Ω). The reduction of the sensitivity at 1 000 Mc/s is 5%. The investigated signal is fed to the deflection system by a coaxial cable with a characteristic impedance of 100 Ω .

A property of the micro-oscillograph is its very large writing field in the horizontal direction (1 000 lines). Thus, with a

sweep time of 10^{-7} sec., a scanning speed of 10^{10} lines per sec. is obtained which is sufficient for displaying pulses with leading edge of 5×10^{-10} sec. and amplitudes 1-2 V. For oscillography of photo-amplifier pulses which are statististically distributed in time, it is more satisfactory not to use a waiting timebase, but to trigger the sweep generator

periodically (for example, at 50 c.p.s). To avoid super-Card2/5 imposition of the oscillograms, it is necessary to move the

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001858820017-1"

120-4-18/35

Investigation of the Shape and Duration of Pulses from Photo-multipliers \$37.19M and \$934-18 using a Micro-oscillograph.

photo-film continuously in a vertical direction. In operation, a 5 cm length of film can contain up to 200 scans and register 5 - 10 random pulses. The method described was used for investigation of the shape and duration of black and scintillation pulses from the output of photo-multipliers of the types (3)/-19M and (3)/-1B.

Fig. la shows a typical micro-oscillogram of a black (single-electron) pulse of the multiplier (3)/-19M with a supply voltage of 2 600 V. The pulse has an amplitude of ~ 2V (on a load of 100 Ω) and corresponds to an electron multiplication of 5 x 10 .

To increase the number of single-electron pulses, a source of γ-radiation (Co⁶⁰) with an intensity of 25 microcuries was placed near the photo-cathode.

Fig. 1b shows a black pulse from the photo-multiplier (3)/-1B (supply voltage 2 800 V). Each of the black pulses of large amplitude is accompanied by a pulse-satellite (Fig la and b). The experiments showed that this accompanying pulse is not due to the oscillographic circuits but rises in the photo-multiplier itself. The time interval between the fundamental pulse and the satellite is constant and is 7 x 10-7 sec. for photo-multiplier for multiplier (3)-19M and 8 x 10-7 sec. for the photo-multiplier

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120-4-18/35 Investigation of the Shape and Duration of Pulses from Photomultipliers \$\Phi_3\gamma_19\text{M}\$ and \$\Phi_3\gamma_1\text{B}\$ using a Micro-oscillograph.

Oscillograms of scintillation pulses were obtained in a similar manner with correspondingly lower supply voltages. The pulse parameters obtained from the oscillograms are given in the table. Comparing the duration of the leading edges of the black and scintillation pulses, it can be concluded that in the photomultiplier Oscillogram arises on part of the photocathode - the first dinode. Contrarily, in the photo-multiplier Oscillogram arises on part of the photo-cathode - the first dinode. Contrarily, in the photo-multiplier Oscillation pulse of the photo-multiplier of the edge of the scintillation pulse of the photo-multiplier of the edge of the scintillation pulse of the photo-multiplier of the resolving time and the effectiveness of the coincidence circuits can be

improved and also the times of flash of different scintillations

can be measured directly. There are 1 figure, 1 table and 3 references, 1 of which is Slavic.

Card4/5

9,4160

Vasil'yev, G.A.

SOV/109-4-8-25/35

AUTHOR: TITLE:

Transient Characteristics of Photo-multipliers

PERIODICAL: Radiotekhnika i elektronika, 1959, Vol 4, Nr 8.

pp 1377 - 1380 (USSR)

ABSTRACT: The transient characteristics of a photo-multiplier are of practical importance in that they illustrate the time response of the system. Such characteristics can be easily determined indirectly. Thus, if A(t) is the response of a photo-multiplier to a scintillation pulse having a form $\exp(-t/T)$, where T is the constant of the scintillator, the transient of the multiplier is given by:

 $h(t) = A(t) + \frac{1}{T} \int_{-T}^{T} A(\xi) d\xi$ (1).

Therefore, the construction of the transient response is equivalent to the integration of the scintillation pulse response. On the other hand, by differentiating Eq (1) with respect to t, it is possible to obtain the Card1/3

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SOV/109-4-8-25/35

Transient Characteristics of Photo-multipliers

response of the device to a 6-ffinction. Apart from the transient characteristic describing the overall performance of a photo-multiplier, it is necessary to measure the electron spread of the cathode system and the multiplication system separately. The transient response of the multiplication system can be found by integrating the shape of the "dark" pulse. The rise time of the cathode system can therefore be expressed by:

$$\gamma_{K} = \sqrt{\gamma_{L}^2 - \gamma_{MH}^2}$$
 (3)

where T represents the overall rise time of the multiplier and YMH is the rise time of the multiplication system. The output pulses of three types of multipliers were investigated experimentally by employing

a special oscillograph having a bandwidth of over 1 000 Mc/s and a sensitivity of 0.25 V/one-ray thickness. The investigated photo-multipliers were FEU-19; FEU-33 and FEU-1V. The scintillation response of the multipliers

Card2/3

Transient Characteristics of Photo-multipliers

is shown in the upper Figures, 2 and 3: the transient response is illustrated in the lower Figures, 2 and 3. The upper curves of Figure 2 were taken by employing the crystals of stilben or plastic scintillators. The upper curves in Figure 3 illustrate the "dark" pulse response. The numerical results obtained from the graphs of Figures 2 and 3 are shown in the table on p 1379. From the table, it is seen that the overall rise times for the three multipliers range from 3.7 to 10.2 mms. There are 3 figures, 1 table and 4 references, of which 3 are Soviet and 1 English.

SUBMITTED: April 15, 1958

Card 3/3

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001858820017-1"

AUTHOR: Vasil'yev, G.A. SOV/120-59-5-16/46

TITLE: A Travelling-wave Cascade Voltage Multiplier

PERIODICAL: Pribory i tekhnika eksperimenta, 1959, Nr 5,

pp 75 - 80 (USSR)

ABSTRACT: The system, which is considered only theoretically, is that in which rectifier bridges are connected in series in an artificial line (Figure 1). Slater's equations (Microwave Transmission, New York, 1942) are applied; the maximum number of sections that can be used is given by the equation below Eq (7), in which η is the ratio of the wave impedances at the two ends of the line and $\xi=w/w_0$, where w is the working frequency and w_0 is

the cut-off frequency of the first section of the line. (Q has it usual meaning.) Eq (8) allows for the finite capacitance $\mathbf{C}_{\mathbf{n}}$ of the bridge, etc; the factor b must

be less than $2\sqrt{C/C_{m}}$ but must be more than $1/\eta$.

Figure 2 shows the equivalent circuit of the line.

The section containing Eq (9) deals with the best parameters;

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SOV/120-59-5-16/46

A Travelling-wave Cascade Voltage Multiplier

the voltage \mathbf{U}_{0} applied to the sections is given in terms of P_{o} (the power supplied) and Z_{o} and the rectified voltage is given by Eq (10). Figure 3 shows how L and Z must vary along the line (n is the number of some section in the line and N is the total number of Eqs (11) to (13) are conditions to be satisfied for the

theory to be applicable.

The next section deals with the ripple and regulation of the output; the phase shift in the best system reduces the ripple by about a factor 50. Figure 4 shows how the voltage is distributed along the line at no-load. The next section reports briefly a few tests on a 50-section model, with 2C = 0.1 μ F, L = 146 μ H,

 $L_n = 317 \mu H$, Q = 40 (at 300 kc/s, $Z_0 = 54 \Omega$, $Z_N = 80 \Omega$, $\eta = 0.68$ and $f_o = 30$ kc/s. It is stated that the system worked adequately over the range 150 to 1 000 kc/s and

Card2/3

A Travelling-wave Cascade Voltage Multiplier SOV/120-

SOV/120-59-5-16/46

gave 5 kV at 2 mA.

The last section points out that this system has the advantage that modern semiconductor rectifiers and ferrites can be used to make the size and weight small, since there are no components other than the insulators that have to withstand high voltages. There are 4 figures and 9 references, 3 of which Soviet, 2 Swiss and 4 English.

ASSOCIATION: Fizicheskiy Institut AN SSSR (Physical Institute of the AS USSR)

SUBMITTED: August 21, 1958

Card 3/3

S/105/61/000/012/003/006 E140/E963

AUTHOR:

Vasil'yev, G.A.

TTTLE:

Tapered transmission lines for cascade voltage

multipliers

PERIODICAL:

Elektrichestvo, no.12, 1961, 54-59

TEXT: The author solves the equations of a tapered artificial transmission line to determine the conditions under which a cascaded voltage multiplier will have equal voltage increments in each stage. The conditions for physical realizability of such circuits are obtained and it is found that it is necessary to use IC filter sections. An example is given of a tapered line in which the inductance increases and the capacitance decreases with IC = const. With easily obtainable parameter values it was found that at 10 kc/s the number of stages could be of the order of 100. There are 5 figures and 8 references (4 Soviet-bloc and 4 non-Soviet bloc). The English-language references read as follows: Ref.1: Everhart E., Lorrain F., The

Card 1/2

Tapered transmission lines ...

\$/105/61/000/012/003/006 E140/E963

Cockroft-Walton voltage multiplying circuit, Rev. Scient, Inscr, 1953, No.24; Ref.8: Milnor J., The tapered transmission line, Trans. of the AIEE, 1945, v.64.

ASSOCIATION: Fizicheskiy institut im, Lebedev AN SSSR

(Physics Institute imeni Lebedev AS USSR)

SUBMITTED: August 19, 1961

Card 2/2

·26,2351 21,2000 s/089/61/010/004/011/027 B102/B212

AUTHORS:

Balabanov, Ye. M., Vasil'yev, G. A.

TITLE:

A traveling-wave cascade generator - a new source for high-

voltage supply of accelerator tubes

PERIODICAL:

Atomnaya energiya, v. 10, no. 4, 1961, 375-377

TEXT: Cascade generators which are well suited as a high-voltage source for ion and electron accelerators (cf. B. S. Novikovskiy, Atomnaya energiya, 4, vyp. 2, 175 (1958)) have the disadvantage of being very expensive and consuming too much energy in their capacitors (~10⁴ joules). Since 1957 a traveling-wave cascade generator suggested by Vasil'yev (Pribory i tekhnika eksperimenta, no. 5, 75 (1959)) has been tested at the Fizicheskiy institut AN SSSR (Institute of Physics, AS USSR). The circuit (Fig. 1) acts as an LC-filter for the upper frequencies. The bridge rectifier in each stage acts as an additional active load which leads to a decrease of the equivalent factor of the coils. The cascade circuit acts analogously to a section of a long traveling-wave line. In order to have an equal load on all voltage rectifiers at a given current and in order to diminish the harmful power

Card 1/5

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S/089/61/010/004/011/027 B102/B212

A traveling-wave ...

leakage in the matching resistor R, the LC-filter has to be inhomogeneous. The characteristic resistance of the cascade has to increase, which is obtained by either increasing the inductance or by simultaneously increasing the inductance and decreasing the capacitance of the discharge capacitors. Such a circuit may have up to 1000 stages; nevertheless, the capacitance of the capacitors in each stage are not lower than in standard circuits. The dimensions of the induction coils for such a circuit have to be large. In order to keep the dimensions of the whole unit within reasons, the coils are made as flat, closely connected discs, each of which is inductivily coupled with 10-20 stages. This design will also decrease the thermal losses in the coils. In a traveling-wave generator circuit, the total pulsation will not exceed that of a single stage in its order of magnitude. A considerable phase shift (100-150°) between the alternating voltages in neighboring stages brings about a compensation of the pulsation. The capacitance of a high-voltage electrode with respect to ground (several 10 µµf) is here considerably higher than the output capacitance of a multiplier circuit (10 puf). This also brings about a suppression of pulsations. With ~0.01% this is within tolerable limits. In order to investigate the properties of this cascade generator, the authors have built a unit

Card 2/5

A traveling-wave ...

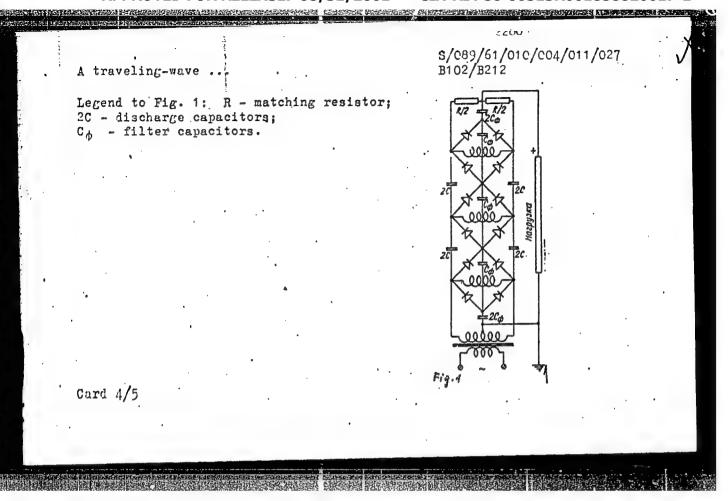
3/089/61/010/004/011/027 B102/B212

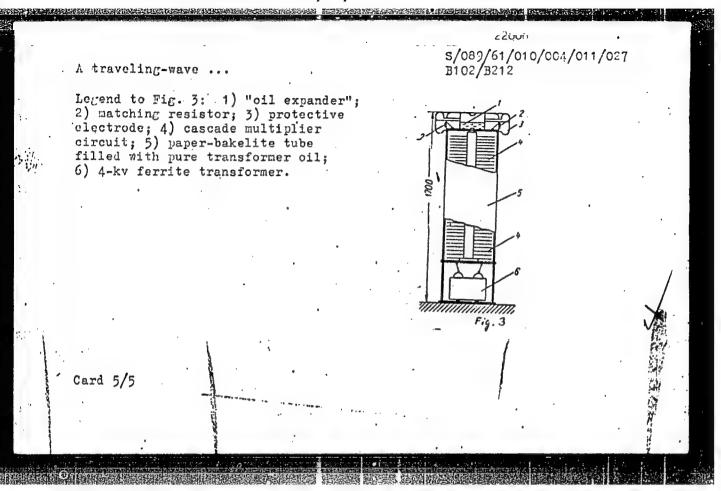
(schematically shown in Fig. 3) with 50 stages (250 kv, 1.5 ma, 7-10 kc/sec). Each stage was 25 mm high. Ceramic capacitors of type KEKE-1 (KVKB-1) with a rated capacitance of 68 μμf and selenium rectifiers of type ABC-7-3E (AVS-7-3P) have been used. The induction coils showed a quality factor of Q = 100-120 at 8 kc/sec. Each stage of the filter column consisted of four parallel-connected capacitors of the type POS (POV) with a total capacitance of 1500 μμf. The unit has been used successfully for the voltage supply of an accelerator tube. The following advantages of this circuit are emphasized: 1) the possibility of using the same compressed gas for insulation in the system and also as a dielectric in the capacitors; 2) low response time (~ 10 μsec); 3) elimination of excessively high alternating voltage of elevated frequency and of corona discharges associated with it; 4) facilitation of work with semiconductor rectifiers; 5) the possibility of connecting the electrodes directly (without voltage divider) to the accelerator tubes. There are 3 figures and 2 Soviet-bloc references.

SUBMITTED: September 22, 1960

Card 3/5

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001858820017-1"





S/105/62/000/004/001/002 E192/E482

9:3230

Vasil'yev, G.A.

AUTHOR:

Distributed network bandpass filter with inductive-

capacitative coupling

PERIODICAL: Elektrichestvo, no.4, 1962, 45-49

TEXT: A multi-section travelling-wave LC network can give voltage multiplication exceeding 100. Constructional considerations favour pancake coils; mutual coupling within groups of 10 to 20 coils give delay-line characteristics. With adjoining coils oppositely wound, the cut-off frequency is reduced and the circuit calculations become those for a distributed transformer. Attenuation, phase-shift and loss curves were thus determined and verified experimentally. Comparison with curves for lumped LC filter networks proved that the loss in the coils was reduced by their mutual coupling. In a specimen calculation, coils with self-inductance L = 1 henry and capacitances 2C = 140 picofarads gave a cut-off frequency of 4 kc/s, a load impedance of 45000 ohms at 10 kc/s and a linear Card 1/2

5/105/62/000/004/001/002 E192/E482

Distributed network ...

Measurements on networks of bandpass width from 5 to 15 kc/s. 20 to 30 coils showed that the terminations needed inductive impedances having a self-inductance 1.5 to 3 times greater than that of the intermediate coils. For minimum attenuation throughout and a high magnification with a given capacitance, the coils, though geometrically similar, had differing numbers of Suggested uses of the network are: series magnification, HF power supply and transmission of signals to h.v.d.c. circuits; efficiencies of 50 to 70% are expected. There are 5 figures.

ASSOCIATION: Fizicheskiy institut im. Lebedeva AN SSSR (Physics Institute imeni Lebedev: AS USSR)

December 30, 1961 SUBMITTED:

Card 2/2

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001858820017-1"

HARRING STATES OF THE PROPERTY OF THE PARTY 1. 44314-65 EWT(1)SOURCE CODE: UR/0205/66/006/004/0618/0619 ACC NR: AP6029426 Vasil'yev, G. A.; Medvedev, Yu. A. AUTHOR: ORG: State Institute for the Advanced Training of Physicians im. S. M. Kirov Leningrad (Gosudarstvennyy institut usovershenstvovaniya vrachey) TITLE: The role of the adrenal cortex in increasing resistance of x-ray irradiated white mice to acute hypoxia SOURCE: Radiobiologiya', v. 6, no. 4, 1966, 618-619 TOPIC TAGS: hypoxia, x ray radiation biologic effect, adrenal gland, radiation tolerance, mouse ABSTRACT: The effect of x-ray irradiation on resistance to acute (anoxic, anemic, and histotoxic) hypoxia was studied in experiments on white mice irradiated with deses of 50, 100, 200, 500, 700, and 1000 r and observed 3 hr, and 1, 2, 3, 5, 6, and 10 days after irradiation. The content and distribution of sudanophilic and anisotropic lipids in the adrenal cortex, and the weight coefficient and size of the adrenals of 50 irradiated mice were determined. Results on the survival of irradiated animals are presented in Table 1. Resistance to acute anoxic hypoxia was increased by doses from 200 to 700 r; the increase was observed by the third hr after 700-r irradiation and lasted 50 days. Resistance to CO and potassium cyanide was also significantly increased by the 700-r dose. Smaller (50- and 100-r) and larger (1000-r) doses gave **Card** 1/3

ACC NR: AP6029426			1				
	Table 1. The effect of x-ray irradiation on survival of white mice in conditions of general bypoxia.					<u>~</u> .	
	Experimental conditions -	Experimental Group Control Group		Cross			
	Experiment Conditions	Survived	Died	Survived	Died		
	Pressure chamber exposures for 10-17 win at an ambtent pressure of 120 cm Mg, beginning 3 hr after 700-r irradiation (29	17	12	8	21		
•	The same after 1 day (47)	26 26	16	13	29		
	- 2 days (40) - 3 days (23) - 6 days (23)	14 14 9	26 11 16	10 11	32 15 14		
	10 days (24)	*	20	8	16		
	Pressure chamber exposures 1 day after 50-r irradiation (15)	5	10	6	9		
•	100 r (20) 200 r (20)	8 11	12	10 7	10 13	ì	
	500 r (25) 1000 r (15)	14	11 11	8 5	17 10		
	Exposure to CO (8 mg/l for 40 min 1 day after 700-r irradiation (20)	15	5	9	11		Н
	Potassium cyanide injection (5 mg (5 mg/kg subcutaneously), 1 day after 700-r irradiation (14)	9	5	4	10		
	Note: Number of animals, in pares experimental and control p		4 the same	for			
	Table 1. The effect survival of white mics in condition						
ard 2/3							

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ACC NR: AP6029426

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no protection. No changes were noted in the weight coefficient or size of the adrenal cortex in mice examined one day after 100- and 1000-r irradiation. The 700-r dose produced statistically significant hypertrophy of the cortex and an increase in weight coefficient by the third postirradiation hr, with the weight coefficient reaching twice normal value by the 2nd, 3rd, 4th, 6th, and 10th postirradiation days. A slight decrease in sudanophilic and increase in anisotropic lipoids was observed in the external branches of the fascicular cortical zone in animals examined the first day after 100-r irradiation, compared to a sharp drop in anisotropic lipoid content and change in the aggregate lipoid state of the protoplasm of the fascicular cells with the 1000-r dose. The 700-r dose produced a gradual decrease in sudanophilic and anisotropic lipoid content from the third hr to the fourth day after irradiation when it reached zero, and a sharp increase on the 6th and 10th postirradiation days, thus confirming an increase in functional activity of the adrenal cortex for the first four days after 700-r irradiation. It was concluded from a comparison of data that the increased resistance of irradiated mice to different types of hypoxia is a nonspecific reaction effected through the adrenal cortex. Orig. art. has: 1 table. [SW]

SUB CODE: 06/ SUBM DATE: none/ ATD PRESS: 5073

Card 3/3

VASILIYEV, G.A.; MEDVEDEV, Yu.A.; PROCORCUSALY, V.B.; MEDITIONALS, L.V.

Effect of accidentization to hypoxia on the grown and redicancitativity of rat hypoxementa. Not. red. 10 m. 2016-20 y 165.

1. Kurs farmakologii (zav. V.R. Prozorovskiy) pri kafede patc-fiziologii i farmakologii (zav. - prof. 3.F. Senderizhin) Fetrozavodskogo gosudarstvennogo universiteta.

PHASE I BOOK EXPLOITATION

SOV/5916

riunov, L. A., G. A. Vasil'yev, and V. P. Paribok

Protivoluchevyye sredstva; spravochnik (Antiradiation Measures; Handbook)
Moscov, Ind-vo AN SSSR, 1961. 171 p. Errata slip inserted. 5000 copies
printed.

Sponsoring Agency: Akedemiya nauk SSSR. Institut tsitologii.

Ed.: V. P. Paribok, Doctor of Medical Sciences, Professor; Tech. Ed.: R. A. Zamarayeva.

FINPOSE: This handbook is intended for physicians, public health doctors, and medical research workers who are specializing in radiation medicine.

COVERAGE: The book contains data on more than 500 antiradiation preparations which have been tested with varying degrees of success on different types of animals, plants, microorganisms, etc. to determine their effectiveness as prophylactic agents against radiation affections. The authors have

Card 1/

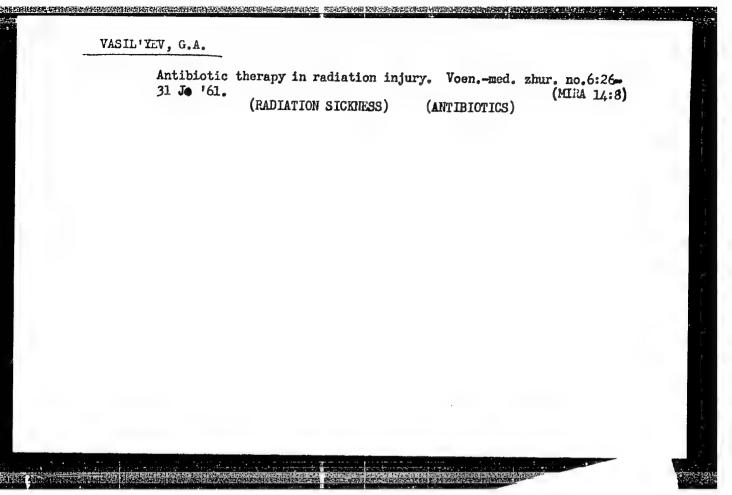
Antiradiation Massures; Handbook

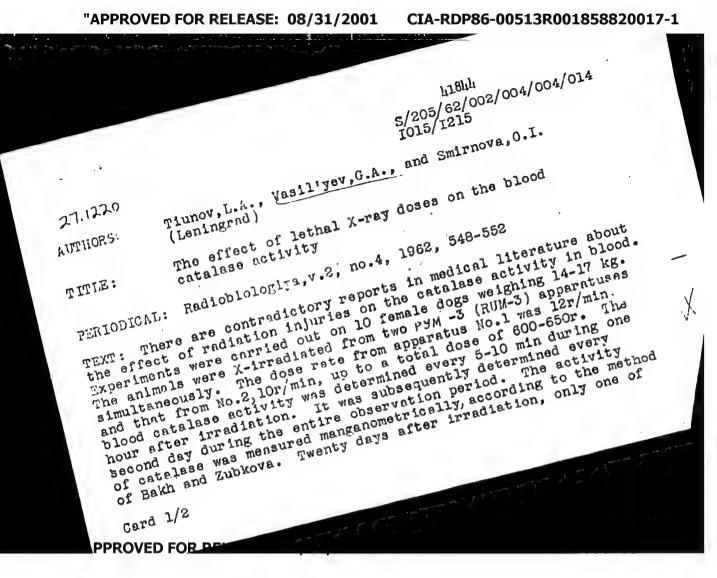
sov/5916

attempted to present in summary form the most important data published to date in the field and to provide a ready guide or standard for measuring the effectiveness of the more recent antiradiation preparations as they are developed. The material is arranged in alphabetical order. In the absence of any special definition, radiation means x-radiation. No personalities are mentioned. Some references appear in the text.

TABLE OF CONTENTS:

Preface		3
Table 1.	Doses and Effects of Antiradiation Preparations	5
Table 2.	Combined Application of Medicinal Preparations for the Fromhylaxis of Radiation Affections	141
Table 3.	Clinical Use of Certain Antirediation Preparations	150
Card 2/3		





S/205/62/002/004/004/014 I015/I215

The effect of lethal X-ray doses...

the dogs survived. The other animals survived on an average 14.9 days. The blood catalase activity decreased within 5 min after irradiation, and reached its maximum decrease after 20-30 min. The low activity level remained during the subsequent days, with a maximum decrease on the 18th day (one third of the normal). It reactions of the organism to radiation injuries. There are 2

SUBMITTED: February 5, 1962

Card 2/2

(MIRA 16:2)

Protective effect against X rays of the adaptation to hypoxia in combination with an acute hypoxia. Radiobiologiia 3 no.1:

117-120 63. (ANOXIMIA) (X RAYS—PHYSIOLOGICAL EFFECT)

YEVDOKIMOV, Aleksandr Ivanovich; [ASIL'YEV, Georgiy Andreyevich; Prinimal uchastiye ZAUSAYEV, V.I., dots.; PROKHONCHUKOV, A.A., red.

[Surgical stomatology] Khirurgicheskaia stomatologiia. Izd.2. perer. Moskva, Meditsina, 1964. 481 p. (MIRA 17:7)

VASILYEV. G. A.

"Tenth Meeting on Problems in Physiology."
Doctor of Biological Science.
Vest. Ak. Nauk SSSR, No. 6, 1944.

Report U-1551, 7 November 1951.

VASIL YEV. G. A.

Doctor or Biological Sciences

"Proceedings of the General Assembly of the Academy Science, USSR 14-17, October 1944" West. Ak. Mauk SSSR, No. 11-12, 1944.

BR-52059019

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001858820017-1"

VASIL'EV, G. A.

"Thorndike's method of problem cells and the method of conditioned reflexes." by Vasil'ev. G. A. (p. 295)

SO: Journal of General Biology (Zhurnal Obshchei Biologii) Vol. X, No. 4, 1949

VASIL'YEY, G. A.

29823

Nyekotoryye osobye-nnosti vysshyey nyervnoy dreyatyel' nosti Losh-adyey. Fiziol. zhurnal ESSR. Im. Syechye-nova, 1949, No. 5, S. 525-34

GOLUBYEVA, N. M.

Sm. 29824

SO: LETOPIS' NO. 40

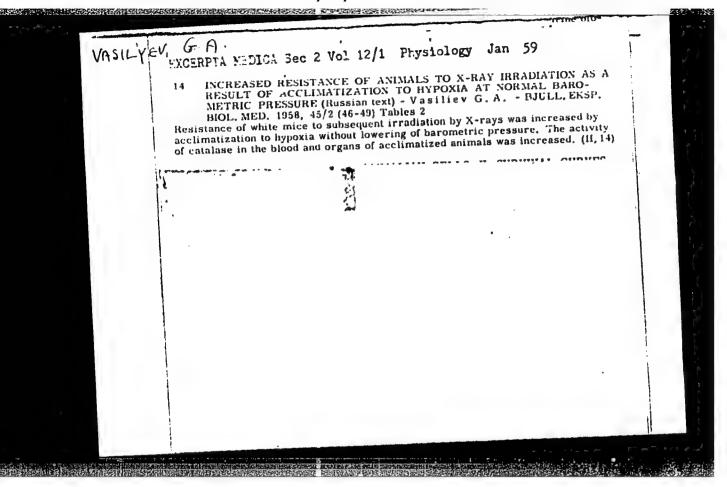
VASILYEV, G. A. I

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7881. VASILYEV, G. A. I Vasil'chenko G. S. Izucheniye eksperimental'nykh nevrozov v ssha. (Po materialam konferentsii 1952 g. v N'yu-yorke). M., Medgiz, 1954. 60 s. 22 sm. 5.000 EKZ. 1R. 60 K.—(55-3572) P

612.82 / 616.8

SO: Knizhuaya Letopis', Vol. 7, 1955



VASILIYEV, G.A.

Acclimatization to hypoxia associated with the administration of cystamine and cyst eamine as a method for preventing radiation sickness [with summary in English]. Med.rad. 4 no.1:41-44 Ja 159.

(MERCAPTOETHY LAMINES,

cystamine & systemmine ther. with anoxic acclimatization in radiation protection in animals (Rus))

(RADIATION PROTECTION, cystamine & cysteamine ther. with anoxic acclimatization in animals (Rus))

(ANOXIA, exper.

acclimatization with cystamine & cysteamine ther. in radiation protection (Rus))

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KIOSOVSKIY, B.N., prof.; VOLZHINA, N.S.; VASIL'IEV, G.A. (Moskva)

Physiology of the optic thalamus. Vop.neirokhir. 23 no.6:1-6

H-D'59.

1. Laboratoriya po izucheniyu razvitiya mozga Instituta pediatrii

AMN SSSR i laboratoriya patofiziologii vysshey nervnoy deyatel'
nosti Instituta nevrologii AMN SSSR. 2. Chlen-korrespondent AMN

SSSR (for Klosovskiy).

(THALAMUS)

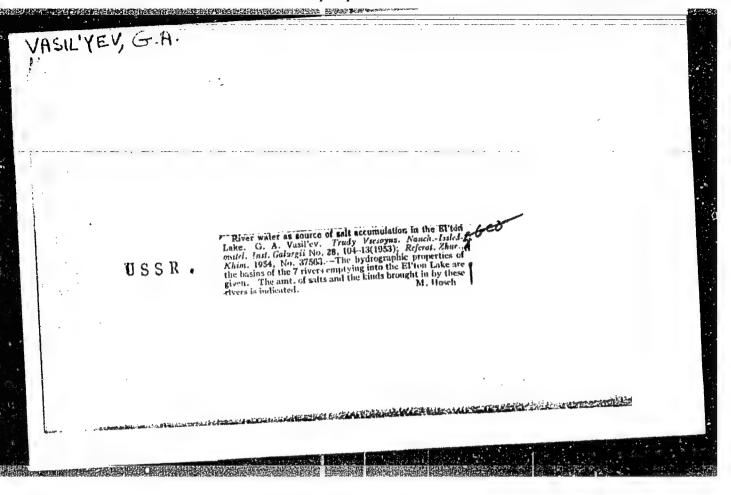
physiol.)

KLOSOVSKIY, B. N.; VASIL'YEV, G. A.; VOLZHINA, N. S.

Sequelae in extirpation of the optic thalami; technique for their removal, nervous status, behavior and conditioned reflex activity of dogs lacking the optic thalami. Nauch. trudy Inst. nevr. AMN SSSR no.1:364-372 '60. (MIRA 15:7)

1. Institut nevrologii AMN SSSR i Institut pediatrii AMN SSSR.

(OPTIC THALAMUS_SURGERY)
(CONDITIONED RESPONSE)



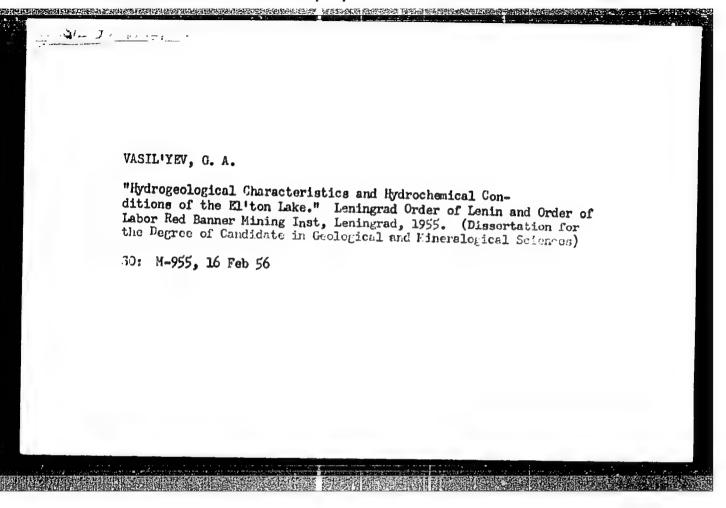
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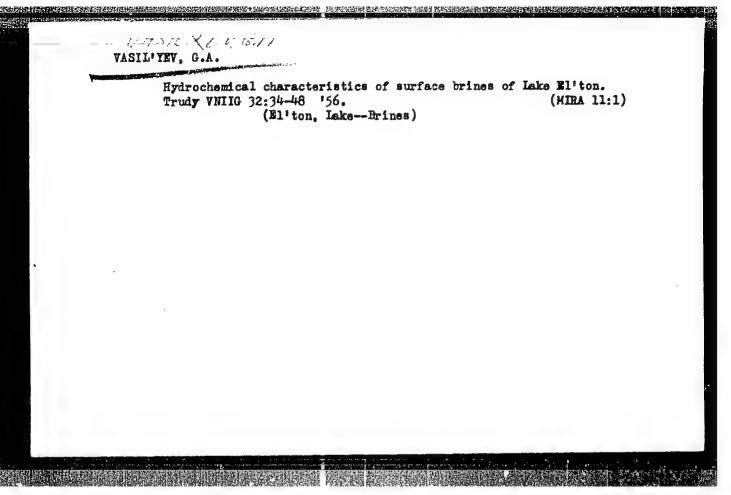
VASIL'YEV, G. A.

"Thermal Regime of the Bottom Brine in the Upper Salt Strata of Lake El'ton"
Tr. Vses. N. -I. In-ta Galurgii, No 28, 114-117, 1953

Investigations of salt deposits and mineral waters. The author publishes the results of works carried out by the All-Union Scientific Research Institue of Halurgy in 1948-1950. The temperatures of the bottom brine for 1949 at various depths according to observations in 10 wells are presented in a table. The characteristic feature of brine temperatures of a lake is the small variation of the mean yearly temperature with depth and the strong smoothing out of the amplitude of mean monthly temperatures with increasing depth of the layer. (RZhGeol, No 3, 1954)

so: W-31187, 8 Mar 55





DZENS-LITOVSKTY, A.I.; VASIL'YEV, G.A.

Geologic conditions governing the formation of bottom sediments in Kara-Bogaz-Gol in connection with fluctuations in the Caspian Sea level. Izv.AN SSSR.Ser.geol. no.3:101-109 Mr '61. (MIRA 15:2)

J. Vsesoyuznyy nauchno-issledovatel'skiy institut galurgii, Leningrad. (Kara-Bogaz-Gol (Gulf)--Deep-sea deposits) (Caspian Sea)

EPF(n)-2/EWT(m)/ETC(f)/EWG(m) ACC NR. AP5026441 SOURCE CODE: UR/0089/65/019/004/0354/0359 28 AUTHOR: Vasil'yev, G. A.; Veselkin, A. P.; Yegorov, Yu. Moiseyev, G. G.; Pankrat yev, Yu. V. 8 ORG: None TITIE: Attenuation of pile radiation in serpentinite sand SOURCE: Atomnaya energiya, v. 19, no. 4, 1965, 354-359 TOPIC TAGS: nuclear reactor material, nuclear reactor shield ABSTRACT: The use of serpentine rock for biological shielding oussed. This mineral is found widely distributed in the Urals, Caucasus Siberia and Kazakhstan, usually associated with asbestos deposits such as the Bazhenov quarries where pure serpentinite monoliths of about 1 cu m were excavated. Its bound water is liberated only at temperatures exceeding 450°C. Thus it can be used as a heat-resisting material for biological shielding. The concentration of hydrogen nuclei in serpentite being about 1.5% by weight, is quite sufficient for insuring the attenuation of fluxes composed of intermediate and fast neutrons. The density of monolithic serpentinite is about 2.6 ton/cu m while the thermal conductivity varies between 2.16 and 2.56 kcal/m.hr. C. This material could be easily but... The compression strength of blocks made of serpen-**Card** 1/3 UDC:

L 28032-66 ACC NR: AP5026441

timite reaches 600 kg/sq om. The shielding properties of serpentinite fine sand (from Bazhenov deposits) were tested in a water-cooled and water-moderated research reactor. The boxes filled with sand were placed close to the core vessel. The maximum thickness was about 180 cm The sand density was 1.62 ton/cu m. The chemical composition given in a table shows that the serpentite sand includes 38.83% of SiO2 and 37.39% of MgO. The investigations were carried out assumming "semi-infinite" and "energy barrier" geometry. The method of induced activity was used for determining the neutron flux attenuation, while the gamma dose rate was measured by means of a scintillation desimeter. The macroscopic cross-section for fast neutrons in sand was calculated as 0.0602 cm-1 of which 45% was due to oxygen and 21% to hydrogen. The variations of cross sections in serpentite and its main components for different levels of fast neutron energy was shown in a graph. in curves reflected the dependence of cross-sections upon the presence The peaks and dips of oxygen. The attenuation of fast neutrons calculated on the basis of threshold measurements is also graphically illustrated. From these graphs and a table, it follows that the relaxation of neutron in serpentite sand is the same as in boron carbide. The protective properties of serpentite monolithical blocks are considerably higher than those of iron ore concentrates and only slightly better than those of serpentinous concrete. The spectra of fast neutrons were also determined and the

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ACC NR. AP5026441

energy distributions at 0, 30, 60, 100 and 140-cm thickness were plotted for various values of neutron flux. The greatest changes were observed for energy levels from 3 to 8 MeV. The relaxation length varies from 14.9 to 17 cm. The flux attenuation for thermal and epithermal neutrons was also investigated. A certain accumulation of neutrons was observed at small serpentite thicknesses. The relaxation was about 15.2 cm. This length is smaller than that (about 20 cm) obtained for iron ore concentrates. The attenuation of dose rates of fast and intermediate neutrons was the same for tested layer thicknesses. The dose relaxation was 15.2 cm. The gamma dose attenuation was 22 cm for a serpentite layer of 270 g/sq cm. The experiments showed that the serpentite sand is as good as the boron carbide. In conclusion, it was stated that the serpentite is not as good as the iron ore concentrate, although the monolithic serpentite has a lower relaxation length. The serpentite shielding properties could be improved by using a mixture consisting of 25% of serpentite and 75% of iron. The full neutron dose relaxation will be about 9 cm. ORIG. art. has: 4 tables and 5 graphs.

SUB CODE: 18 / SUBM DATE: 29Jan65 / ORIG REF: 11 / OTH REF: 3

Card 3/3 CC

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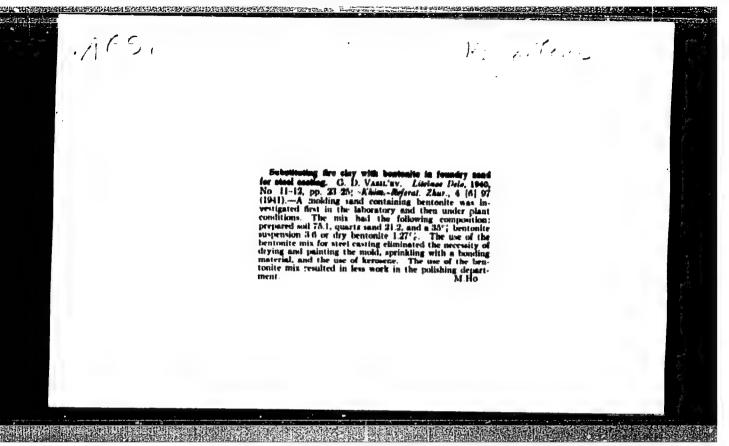
VASIL'YEV, G.D.; TRAVINA, I.O.

Some materials on the exploration of spawning grounds of Atlanto-Scandinavian herring in April and May [1959]. Trudy BaltNIRO

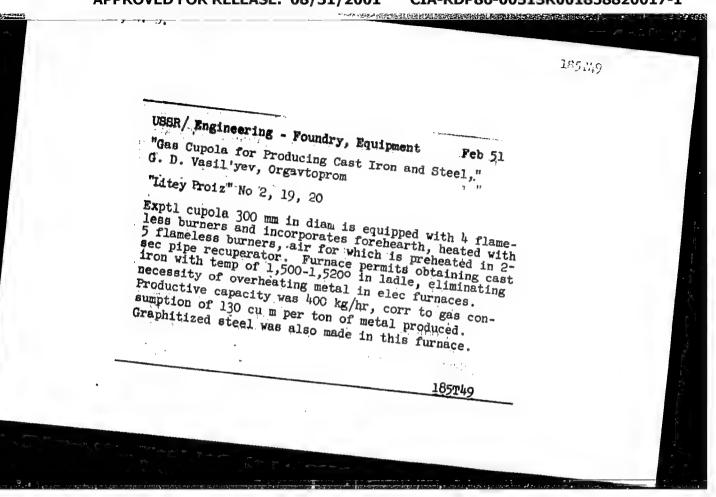
no.7:63-66 '61.

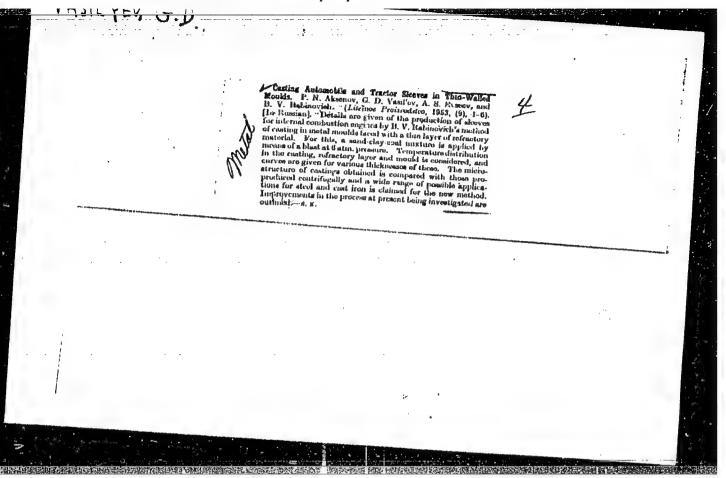
(North Sea--Herring)

(MIRA 15:2)



h is connected to suction pump, ber to be installed on mold. dure and equipment.	collector, which is and vacuum chamber Describes procedure
185T45 g - Foundry, Equipment Jan 51 (Contd)	USSR/Engineering
Method is used at Gor'kiy Automobile Plant for casting GAZ-51 cyl blocks. It considerably decreases rejection of castings (sometimes by 30%) and permits use of molding and core mixts of increased strength. Installation basically consists of 4 flexible steel hoses attached to	Method is used at Gor' casting GAZ-51 cyl blo decreases rejection of 30%) and permits use of increased strength. consists of 4 flexible
Vo 1, pp 30, 31	"Litey Proiz" No 1, pp 30,
g by the Method of Selective Suc- "G. D. Vasil'yev, A. M. Polevaya, avtoprom	"Vacuum Pouring by the tion of Gases," G. D. Engineers, Orgavtoprom
ag - Foundry, Equipment Jan 51	ussr/en





VASIL'YEV. G.D., inzhener; VITKIND, L.M., inzhener; MODEL', B.I.,

[Oilless binder "P" for core production] Sterzhnevoi bezmaslianyi krepitel; "P". Moskva. Gos. nauchno-tekhn. izd-vo mashinostroit. i sudostroit. lit-ry, 1954. 49 p. (MLRA 7:8)

1. Moscow. Gosudarstvennyy Vsesoyuznyy institut avtomobil'noy tekhnologii.
(Founding)

USSR/Electronics - Electronic and Ionic Emission

H-2

Abs Jour

: Referat Zhur - Fizika, No 5, 1957, 12282

Author

Yelinson, M.I., Vasil'ev, G.F.

Inst

Title

: Cold Cathode Emission of Tantalum.

Orig Pub

: Zh. tekhn. fiziki, 1956, 26, No 8, 1669-1670

Abstract

: Short results are given on the investigation of the emission from tantalum points 0.3 -- 0.8 micron in diameter. The investigations were made by means of a spherical or

conical Mueller projector.

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APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001858820017-1"

PA - 2576

Study of the method applied for reduction of autocathode bombardmentby the ions of residual gases.

vantages. The various technological methods worked out by the authors are described. These methods permit all operations to be undertaken with high accuracy and convenience. The process of electrochemically cauterizing the wire point was especially simplified. The various experiments are described, e.g.

- with active adsorbing films by means of two different methods.
- 2. experiments of bombarding points of pure tungsten with mercury ions, and
- 3. tests for the determination of the life of valves and the peculiarities of emission connected herewith.

The system with a strong asymmetric configuration of the electric field is the best means of reducing the detrimental effect of ion bombardment. (21 illustrations)

ASSOCIATION: not given.

PRESENTED BY: -

SUBMITTED: 30. 7. 1956

AVAILABLE: Library of Congress.

CARD 2/2

VASIL'YEV,G.F.

PA - 2598

AUTHOR: TITLE:

Experimental Research of the Field Emission of Hexaborid Lantan. (Eksperimental'noye issledovaniye avtoelektronnoy emissii

Radiotekhnika i Elektronika, 1957, Vol 2, Nr 3, pp 348 - 350

PERIODICAL: (U.S.S.R.) Reviewed: 6 / 1957

Received: 5 / 1957

ABSTRACT:

Compressed and caked together rods of LaB6 with a diameter of 1 mm and a length of 15 mm served as initial object. Investigation of the emission characteristics was carried out in autoelectron diodes. The usual measuring scheme was used. At some of the characteristics a tendency towards saturation was observed. Between these sections there are some "steps". It was shown that these "steps" are not connected with any nonreversible phenomena whatever. The appearance of the characteristics confirms that the borid, cooled to room temperature (after a treatment at high temperature), at least in the layer bordering on the surface, is a semiconductor. The existence of several steps (and not, as it ought to be according to the theory by R.Stratton (Proc.Phys.Soc. B., 1955, 68, 430 B, 746 - 757) only one) may be connected with the fact that for different places of the emitter the electric field is different and the breaf-through of the barrier takes place successively at different places and at different orders of u.

Card 1/2

APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001858820017-1"

PA = 2598 Experimental Research of the Field Emission of Hexaborid Lantan.

It is, however, also possible that these steps are connected with the polycrystalline shape or with the presence of some energy levels of the electrons on the surface. Preliminary experiments showed that the LaB₆ emitter possesses sufficient stability. At present further

investigations of the substances described are being carried out. (4 illustrations).

ASSOCIATION: Not given.

BRESENTED BY:

SUBMITTED:

AVAILABLE: Library of Congress.

Card 2/2

. VASILYEV, G.F.

PHASE I BOOK EXPLOITATION

SOV/1804

Yelinson, Mordukh Il'ich, and Vasil'yev Gennadiy Fedorovich

Avtoelektronnaya emissiya (Electron Field Emmission) Moscow, Fizmatgiz, 1958. 272 p. 6,000 copies printed.

Ed.: Ye. L. Starokadomskaya; Tech. Ed: N. Ya. Murashova.

This book is intended for engineers and technicians working in electronics and can also be useful to upper division and graduate students PURPOSE: specializing in this field.

COVERAGE: According to the authors this book is the first systematic presentation of the results of theoretical and experimental work in the field of electron field emission. The authors see the possibility of practical application of this phenomenon to radio physics and electronics. The introduction is a short exposition of basic data on the energy distribution of electrons in crystals and on the nature of the potential barrier at the boundary of metals and semiconductors (dielectrics) in a vacuum. Chapters 1 and 2 cover the theory and experimental research in electron field emission or metals. In Ohapter 3 the author examines

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APPROVED FOR RELEASE: 08/31/2001 CIA-RDP86-00513R001858820017-1"

Electron Field Emission

sov/1804

the cause of the non-stability of emission and possible ways of increasing the stability of emission characteristics. In Chapter 4 the authors examine the theory and extremely limited experimental research done in field emission of semiconductors. In Chapter 5 the authors discuss aspects of the problem of nonmetallic complex autoelectronic emitters. Chapter 6 contains data on the use of electron field emission in the cathodes of electron equipment and in electron-emission microscopes of high resolving power. M.I. Yelinson wrote the Introduction and Chapters 1, 3, and 5. Chapters 1, 4, and 6 were written by M.I. Yelinson with the cooperation of G. F. Vasil'yev. The authors give recognition to D. V. Zernov, Corresponding Member of the Academy of Sciences recognition to D. V. Zernov, T. I. Kofanova, and A. A. Yasnopol'skaya for the USSR, and V. A. Gor'kov, T. I. Kofanova, and A. A. Yasnopol'skaya for their help in compiling the volume. There are 243 references, 84 of which are Soviet, 35 German, 3 Japanese, and 120 English.

TABLE OF CONTENTS:

Editor's Preface

Authors Preface

Introduction

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5

7

11

307/109-3-7-10/23

AUTHORS: Yelinson, M.I. and Vasil'yev, G. F.

Investigation of the Field Emission of, Lanthanum Hexaboride (Issledovaniye avtoelektronnoy emissii geksaborida lantana) TITLE:

PERIODICAL: Radiotekhnika i elektronika, 1958, Vol 3, Nr 7, pp 945-953 (USSR)

ABSTRACT: The work described aimed at the investigation of the field emission of LaB6, in particular, the investigation of the mechanism of the emission, the adsorption properties, and chemical stability when subjected to ion bombardment. The investigated samples were in the form of bars having dimensions 1.5 x 1.5 x 20 mm. These were shaped into sharp points by means of etching baths, the best results being obtained by electrolytic etching in concentrated sulphuric acid by using direct current. The points were then washed The emissive points were then degassed; several methods were tried (as illustrated in Fig. 2) and it was found that at temperatures below 1300°C a thin dielectric film was formed on the points; this could be eliminated if the samples were heated up to 2000°C. First, the emission patterns of the samples were taken; Fig. 4a shows the emission pattern of a cold point, while Fig.4b illustrates the pattern of a sample heated to a temperature of 850°C.

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307/109-3-7-10/23

Investigation of the Field Emission of Lanthanum Hexaboride

The voltage current characteristics of various samples are shown in Fig.5. Curves a and b of Fig.5 correspond to emitter temperatures of 0° and 850°C, respectively; Curve 1 of the figure was taken immediately after heating the of the figure was taken immediately after heating the 60 and 90 minutes after beating. A typical graph of the emission current as a function of time is illustrated by emission current as a function of time is illustrated by correct 1 in Fig.6; Curve 2 in the figure shows the current Curve 1 in Fig.6; Curve 2 in the figure shows the current for the case when the voltage was randomly interrupted. Fig.7 shows voltage-current characteristics of a LaB emitter immediately after heating to a temperature of 1500°C, and immediately after heating to a temperature of 1500°C, and then 15 minutes after the completion of the heating cycle; two similar curves for the heating cycle up to 850°C are two similar curves for the heating cycle up to 850°C are also shown. From Fig.7 it is concluded that the work function of the emitter increases by about 60% when the sample is subjected to poisoning and, secondly, that the mass of the adsorbed gases is eliminated at 850°C. The

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SOV/109-3-7-10/23

Investigation of the Field Emission of Lanthanum Hexaboride

temperature dependence of the field emission current is illustrated by the curves shown in Fig.8. A number of samples were subjected to pulse tests at voltages ranging from 9 to 20 kV and at current densities of the order of 107 A/cm². It was found that a vacuum-type arc discharge was formed when the current densities were excessive. The effect of ion bombardment on the emission was investigated by measuring voltage u(t) for constant currents, at various pressures of the bombarding mercury. The results are shown in Fig.9 for pressures ranging from 10-7 up to shown in Fig.9 for pressures ranging from 10-7 up to 3 x 10-7 mm Hg; the figure shows similar curves for tungsten and rhenium. A large number of the voltage current characteristics measured by the authors differed from the standard straight lines, which normally characterise the field emission of metals. Consequently, it was thought that the emission mechanism in LeB6 is different from that of metals. It was found, however, that the main cause of the non-linearity is the poisoning of the emitters during the measurement of the characteristics (lasting up to 10 sec). By employing an oscillograph the time of measurement could

Card 3/4

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我是自然自然的,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是一个人的。""我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是一个人

SOV/109-3-7-10/23

Investigation of the Field Emission of Lantanum Hexaboride

be reduced to less than 0.5 sec and it was found that the voltage current curves were linear, as shown in Fig.10. The paper contains 10 figures and 4 references, 2 of which are Soviet and 2 English.

SUBMITTED: November 29, 1957.

- 1. Lanthanum borides—Adsorptive properties 2_{i^*} ;Lanthanum borides—Chemical properties 3. Lanthanum borides—Bombardment
- 4. Ion bombardment 5. Field emission-Analysis

Card 4/4

SOV/109-3-7-16/23

AUTHOR: Vasil'yev, G. F.

TITLE: On the Problem of the Theory of Field Emission of Semi-Conductors (K voprosu o teorii avtoelektronnoy emissii poluprovodnikov)

PERIODICAL: Radiotekhnika i elektronika, 1958, Vol 3, Nr 7, pp 962-964 (USSR)

ABSTRACT: The expression for the emission of the potential barrier at the boundary of a hard substance and vacuum, as derived by Murphy, can be used to develop a theory of the field emission in semiconductors. The transmission coefficient for the barrier is given by Eq.(1), where the various coefficients are defined by Eqs.(2). If the parameter y in Eq.(2) is replaced by my, where m is given by Eq.(3), Eq.(1) is also valid for semiconductors. The number of electrons having normal impulse components (per unit surface and unit time) is expressed by Eq.(4) for the case of degenerate electron gas and by Eq.(5) for non-degenerate electron gas, in Eqs.(4) and (5), 5 denotes the Fermi level, k is the Boltzman constant, T the absolute temperature, and n the concentration of electrons in the conduction zone. The density of the field emission current is expressed by Eq.(9).

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JOV/109-3-7-16/23

On the Problem of the Theory of Field Emission of Semiconductors

electron gas is expressed by Eq.(10); this is applicable within the limits defined by Eqs.(11); the coefficients b, c and d in Eq.(10) are defined by Eqs.(12), (13) and (14). For the non-degenerate electron gas, the emission current is given by Eq.(15), where Φ is expressed by Eq.(16). The applicability of Eq.(15) is defined by the limits given by Eqs.(18). The author expresses his gratitude to M. I. Yelinson for valuable advice and discussion. There are 2 English and 1 Soviet reference.

SUBMITTED: January 20, 1958.

- 1. Semiconductors--Electrical properties 2. Field emission--Theory
- 3. Mathematics

Card 2/2

AUTHORS: Yelinson, M.I. and Vasil'yev, Sov/109-4-4-22/24

Certain Peculiarities of the Field Emission of Germanium TITLE:

(Nekotoryye osobennosti avtoelektronnoy emissii germaniya)

PERIODICAL: Radiotekhnika i elektronika, 1959, Vol 4, Nr 4,

pp 728 - 729 (USSR)

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Card1/#

ABSTRACT: The field emission of n-type germanium was investigated

and the results are shown in Figures 2 and 3. The investigated samples were in the form of bars having dimensions 1 x 1 x 10 mm and were prepared from a crystal

having a resistivity of 2-10 Acm. The bars were

electrolytically etched into fine points (Figure 1). A typical voltage-current curve of this type of emitter is shown in Figure 2; the middle portion of the characteristic

is rectilinear, while in the region of small currents, the characteristic deviates from the linearity; also at large currents the characteristic is non-linear and the current has a tendency to increase. Figure 3 shows two voltage-

current curves taken at two different temperatures; these correspond to comparatively small currents.

Vasil'yev, G.F., Politova, N.M., Shabel'nikova, A.E., AUTHORS:

Pervova, L. Ya. and Yasnopol'skaya, A.A.

Interdepartmental Seminaron Cathode Electronics (The 11th TITLE:

Meeting) (Mezhduvedomstvennyy seminar po katodnoy

elektronike) (11-e zasedaniye)

Radiotekhnika i elektronika, 1959, Vol 4, Nr 4, PERIODICAL:

pp 731 - 732 (USSR)

A meeting of the seminar took place on December 1, 1958 ABSTRACT:

at the Institut radiotekhniki i elektroniki AN SSSR (Institute of Radio-engineering and Electronics of the Ac.Sc.USSR). During the meeting 8 papers were read. Yu.G. Ptushinskiy read a paper entitled: "Kinetics of the Adsorption of Oxygen on the Surface of Tungsten".

The second paper, by I.M. Dykman and S.M. Pekar,

dealt with "The Admixture Photo-Effect of Semiconductors in the Region of the Exciton Light Absorption". The paper by T.L. Matskevich was devoted to "The Problem of

the Secondary Electron Emission of Fine Films of a Number of Organic Substances". The problem of "Surface

Ionisation in a Strong Electric Field on a Surface with Card1/2

SOV 109-4-4-24/24 Interdepartmental Seminar on Cathode Electronics (The 11th Meeting)

a Non-homogeneous Work Function" was considered by E.Ya. Zandberg and N.I. Ionov. I.N. Bakulina and N.I. Ionov read a paper entitled "Determination of the Electron Attachment Energy and of the Potentials of Atoms by the Method of Surface Ionisation". N.L. Yasnopol'skiy and A.P. Alekseyevadealt with the problem of "Passage of Steady-state Currents Through a Dielectric When the Current Carriers Arc Introduced Through One of the Contacts by Means of Electron Bombardment". The lecture by D.A. Ganichev and K.G. Utkin discussed the following -"The Possibility of the Analysis of the Total-energy Distribution of Electrons in a Quasi-spherical Condenser". The work by M.L. Kapitsa, S.A. Fridrikhov and A.R. Shullman dealt with an investigation of the secondary electron emission and the characteristic energy losses of a number of dielectrics (glass, mica, fluorite and alkali-haloid monocrystals).

Card 2/2

USCOMM_DC-60997

VASIL'EV, G.F. Cand Phys-Math Sci (diss) " I.vestication of the electrostatic emission of certain refractory compounds with semiconductor and metallic conductivity," Tashkent, 1960, 14 pp (Tashkent State University im V. 1. Lenin) (EL, 39-60, 113)

CIA-RDP86-00513R001858820017-1 "APPROVED FOR RELEASE: 08/31/2001 为,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们也没有一个人的,我们也没有一个人的,我们就是 第一天,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是一个人的,我们就是

5/109/60/005/011/012/014 E140/E485

9,3140 (2301,1003,1140)

Vasil'ygy, G.F. AUTHOR:

Influence of the Shape of Potential Barrier at the TITLE:

Emitter-Vacuum Interface and the Electric Field Distribution Over the Emitter Surface on the Shape of

88163

Volt-Ampere Field-Emission Characteristics

PERIODICAL: Radiotekhnika i elektronika, 1960, Vol.5, No.11,

pp.1857-1861

Recently published work (Ref.1) have shown anomalous behaviour of the volt-ampere field emission characteristics in the neighbourhood of field strength 8.107 V/cm. authors explain the observed behaviour by the presence of space charge above the emitter surface. The present article is based on the image-field approach to this problem, calculating the image forces, however, with a correction for the atomic structure of the Further, the field strength at the emitter surface is calculated on the basis of an analytic approximation to the commonly used point emitter geometry. It is shown that the purely geometric approach used here can, at least, partially explain the

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88163

S/109/60/005/011/012/014 E140/E485

Influence of the Shape of Potential Barrier at the Emitter-Vacuum Interface and the Electric Field Distribution Over the Emitter Surface on the Shape of Volt-Ampere Field-Emission Characteristics

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anomalous behaviour observed. There are 2 tables and 15 references: 4 Soviet and 11 non-Soviet.

SUBMITTED: March 31, 1960

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Card 2/2

20421 S/109/60/005/012/019/035 E192/E382

9.4300 (1043, 1143, 1150, 1161)

AUTHORS: Yelinson, M. I., Zhdan, A.G. and Vasil'yev, G.F.

TITLE: Interpretation of the Shape of Voltage-current Characteristics of the Field Emission in Semi-

conductors

PERIODICAL: Radiotekhnika i elektronika, 1960, Vol. 5, No. 12, pp. 2004 - 2008

TEXT: A typical voltage-current characteristic in lg j and 1/E coordinates for metals is in the form of a straight line for a wide range of currents i and voltages u. Such a characteristic is shown in Fig. 1. However, at current densities j > 7 x 10 A/cm a considerable deviation from the linearity is observed. Thus, a characteristic bendappears in the vicinity of the point A (Fig. 1) which occurs at lower j. Further, in the vicinity of the point B the rate of the current increase becomes greater again. The deviation at the point A can be explained by the effect of the space charge of the emitted electrons and by the deviation of the true form of the potential barrier Card 1/6

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Interpretation of the Shape of Voltage-current Characteristics of the Field Emission in Semiconductors

from the classical law of the image forces. Also it should be taken into account that at high electron energies the transfer coefficient of the potential barrier is given by

$$1 + \exp \left[\frac{4\sqrt{2} \text{ m}^{1/2} | E_x|}{\text{heE}} \right] (y)$$

The reason for the rapid increase of j in the vicinity of point B is not yet clear. For the semiconductors a typical voltage current characteristic for field emission at low temperatures is also in the form of a straight line. However, very often the experimental characteristics deviate from rectilinear form and these deviations can be of various types. Such characteristics for the emitters made of

Card 2/6

20421

S/109/60/005/012/019/035 E192/E382

Interpretation of the Shape of Voltage-current Characteristics of the Field Emission in Semiconductors

SiO₂ + C and Al₂O₃ + C were investigated in an earlier work (Ref. 2). It was found that the possible reason for the deviation of these characteristics from linearity is the influence of the strong internal field in the semiconductor, which changes the distribution function and the electron concentration. The characteristics of SiC. Ge and ZnS (taken from Refs. 3, 4, and 5) are also shown. The peculiarity of these three characteristics is the deviation from linearity at small currents. A new type of voltage-current characteristic was discovered. The materials used in the investigation were semiconductors based on SiO₂ and Al₂O₃. In order to make these emitters conducting, SiO₂ was activated with carbon and tungsten was added to Al₂O₃. The particular feature of these substances is their low electron affinity coefficient to lev (Ref. 2).

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20421 S/109/60/005/012/019/035 E192/E382

Interpretation of the Shape of Voltage-current Characteristics of the Field Emission in Semiconductors

The voltage-current characteristics of three emitters made from SiO₂ + C is shown in Fig. 6. It is seen that the characteristics deviate from linearity at low currents (see point G). These characteristics are novel in that the bend at point G has nothing to do with the barrier produced by the presence of the surface charges since this is overcome at comparatively low electric fields. This is due to the fact that emitters have a very high resistance and in the investigated range of currents they have considerable internal fields. Secondly, the space-charge effect is insignificant due to the fact that the emitted currents are very low. In general, the characteristics of the type shown in Fig. 6 can be obtained at higher temperatures; in fact, at room temperatures the characteristics are often rectilinear while at higher temperatures they have the shape shown in Fig. 6.

Card 4/6

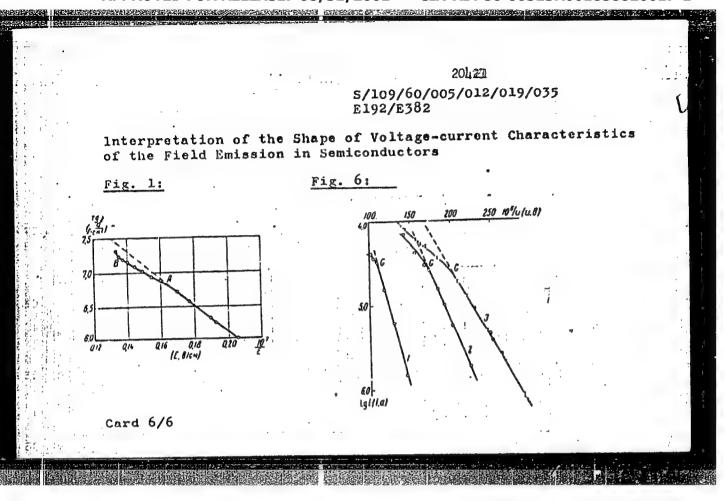
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Interpretation of the Shape of Voltage-current Characteristics of the Field Emission in Semiconductors

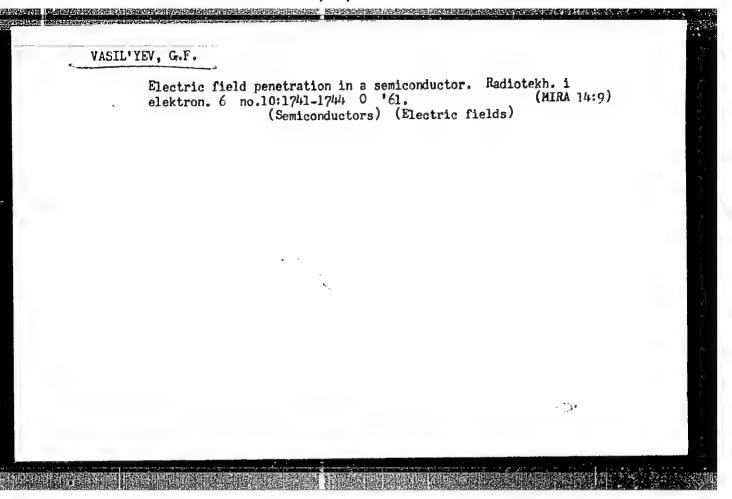
The shape of the characteristics can be explained if it is assumed that $\Theta(y)\simeq 0$, where Θ is the Nordheim function. This means that the potential barrier at the boundary between the semiconductor and vacuum practically disappears and the exponential emission law is replaced by a comparatively slowly increasing function such as $i=kE^2$. There are 7 figures and 6 references: 3 Soviet and 3 non-Soviet.

SUBMITTED: March 12, 1960

Card 5/6



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L 15370-66 EVT(1)/EWP(e)/EVT(m)/T/EWP(t)/EWP(b) IJP(c) JD/GG ACC NR: AP6004471 SOURCE CODE: UR/0048/66/030/001/0071/0074 AUTHOR: Markov, V.S.; Prokopenko, V.S.; Pak, N.G.; Vasil'yev, G.G. ORG: Krasnoyarsk State Pedagogical Institute (Krasnoyarskiy gosudarstvennyy pedagogicheskiy institut) 21.44.55 21.44,55 TITLE: Oscilloscope display of the hysteresis loops of separate parts of a film Transactions of the Second All-Union Symposium on the Physics of Thin Perromagnetic Films held at Irkutsk 10 July to 15 July, 19647 SOURCE: AN SSSR. Ezvestiya. Seriya fizicheskaya, v.30, no. 1, 1966, 71-74 TOPIC TAGS: ferromagnetic film, magnetic thin film, Faraday effect, Kerr effect, hysteresis loop, magnetic anisotropy, ABSTRACT: Equipment employing the Faraday or Kerr effect is described with which one can display on an oscilloscope screen the hysteresis loop of a small region of a ferromagnetic film. In the authors' apparatus a spot of polarized light from several millimeters to several tens of microns in diameter was focused on the investigated film and the reflected or transmitted light (depending on the thickness of the film) was collected, passed through an analyzer, and focused on a photomultiplier. The signal from the photomultiplier was applied to the vertical axis of an oscilloscope, to the horizontal axis of which there was applied a signal proportional to the magnetizing field. A number of exploratory experiments were performed and hysteresis loops are Card 1/2 _

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presented. By recording both the longitudinal and transverse hysteresis loops with different orientations of the film it is possible to map the direction of the anisotropy axis in different parts of the film. The accuracy with which the direction of the local anisotropy axis can be determined is at least great as can be obtained of the local anisotropy axis can be determined in the technique of D.O.Smith (J. Appl. Phys., 32, 70 (1961)), which requires with the technique of D.O.Smith (J. Appl. Phys., 32, 70 (1961)), which requires observation of the domain structure. Orig. art. has: 8 figures.

SUB CODE: 20 SUBM DATE: 00 ORIG. REF: 001 OTH REF: 001

5/122/61/000/011/003/006 D221/D304

AUTHOR:

Vasil'yev, G. G.

TITLE:

The manufacture of plastic dies

Vestnik mashinostroyeniya, no. 11, 1961, 54 - 58

FERIODICAL:

The dies made of plastic material based on epoxy re sin are economical for small batch production, although the plastic is more expensive than metal. Their life can be extended by metal spraying, and the use of copy millers for machining these tools is eliminated. The labor involved is about half of that required for the manufacture of metal dies, because plastic tools are cast. This is done by making a replica in plaster of Paris of the master model. The author describes in detail the actual process, as well model. The author describes in detail the actual process, as well as the casting of the form. In the case of phenolic resin, it is cooled to 13-200, when a hardening agent, called the contact of the cooled to introduced. The composition is mixed and its remember to the contact of the contac Fetrov is introduced. The composition is mixed and its temperature is maintained by water circulation in the jacket of the mixer.

Card 1/3

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The manufacturing of plastic dies

After casting it is held for a day in room temperature, dried and heat treated at 500 during 24 hours, 600 -for 12 hours, and 800 12 hours. The cooling takes place at room temperature. The dies made of phenolic resins are cheaper than those based on eroxy materials, however, their life is shorter, and their use is limited to shallow drawing. The plastic TAK - 3 (TLK-E) is made of resin based on cellulose ester, and is applied for punches in stamping sheet metal parts in board hammers. The working parts of dies made in acrylic resins are reinforced with glass fibres, and form ACT . T (AST-T) plastic. Whenever low specific pressures are required for stamping, then plastic dies are expedient. The plastic section of the tool is joined to the metal part by colts or epoxy route. machining, when this arises, is executed in normal machine tools. The corrosive action of their chips on machine tool components should be taken into account. The high quality epoxy resin facing of the working parts of dies is at present widely used. A forming tool of this kind is designed for operation in a board drop hanner.

Card 2/3

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The manufacturing of plastic dies

S/122/61/000/011/053/006 D221/D304

The epoxy resin adheres well to metal and there is no need for bolt fastening. A hardly noticeable contraction after casting of the form dispenses almost entirely with machining. The author provides details of casting process, as well as the composition of the facing, and a note is made that dies should be made with harder surface than punches. The reduction of cost can be attained by introducing cores of wood, metal or cheap plastic. The practice of the "Karosa" Factory (ChSSR) in this respect is recalled. As examples, some tool designs are illustrated and the procedure of die manufacture is described. Details are also given of the method of metal spraying which ensures a longer life of the tool. Finally the process of facing with plastic of large dies with core made of concrete is discussed. There are 12 figures.

Card 3/3

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VASILAYEV, G. G.

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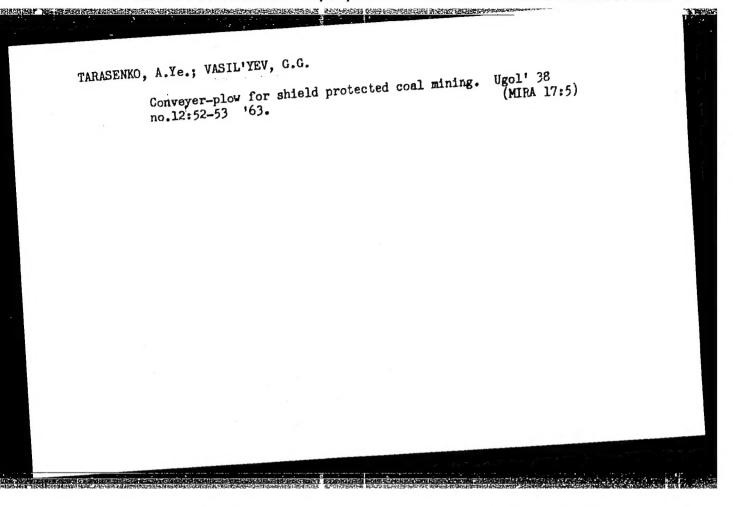
USSR/Metals Steel Plate Strain Measurements

"Determination of the Conditional Yield Limit for High Durability Steels, Rolled Into Plate," G. G. Vasil!yev, Magnitogorsk Metal Combine, 6 pp

"Zavod Lab" Vol XIV, No 10

Complains that old methods of testing subject steel plate are either too slow and laborious or cannot be used for relatively thin plate. Discusses method using Amsler-type machine and amplifying the strain reading 20 times for closer gauging. Method was tested and found much faster, and accurate within 27.

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sov/67-59-5-4/30 Vasil'yev, G. G., Engineer 14(1) On a Uniform Consumption of Liquid Oxygen in Gasifiers AUTHOR: Connected in Parallel TITLE: PERIODICAL: Kislorod, 1959, Nr 5, pp 15 - 19 (USSR) In order to ensure a uniform consumption of liquid oxygen in 4 gasifiers working in parallel, the coefficient of nonuniformity $K=Q_{max}/Q_{min}$ is not to exceed the value of 1.2. ABSTRACT: \mathbf{Q}_{\max} and \mathbf{Q}_{\min} , respectively, denote the maximum and minimum consumption of liquid oxygen per unit of time. To investigate the working conditions for guaranteeing this value K, labo-ratory investigations were carried out. The operation scheme of the gasifiers has already been described in a previous paper. The arrangement of the four gasifiers connected in parallel is shown in figure 1. Besides the common gas outlet pipe, also a connecting gas pressure expansion pipe is installed. The reasons for the nonuniform working were investigated, and explained by the construction of the individual gasifiers. They work at a somewhat different pressure thus Card 1/3

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